Module Handbook

Electronics
Dachalar
Bachelor
FI2103
3/ Second Years
3/ 3000Hu 10013
Bahasa Indonesia
Dariasa maonesia
General Studies / Major Subject / Elective Studies
4 hours lectures
4 hours lectures, 8 hours individual study and Laboratories work, 16 weeks per
semester, and total 192 hours a semester
2
Elementary Physics II
 Knowledge: Ability to explain and describe atom theory, band energy, instrinsic and extrinsic semiconductor, p and n-type semiconductor Ability to explain and describe junction diode theory, diode load line, half and full wave rectification, capacitor filtering, voltage doubler, diode clipper, and voltage regulator Ability to describe the assess of bipolar junction transistor (BJT) amplifier circuits (common emitter, common collector and common base) Ability to describe the assess of field effect transitor (FET, JFET, MOSFET) amplifier circuits (common gate, common sourches and common drain) Ability to describe the operational amplifier (op-amp) circuit, inverting, non-inverting, summing, voltage follower and differential amplifier circuits Ability to describ the basic of digital electronics and carnough map Skill Ability to analyze, calculate and compute Thevenin and Norton Equivalen Circuit Ability to compute, calculate, analyze, design, assess of bipolar junction transistor (BJT) amplifier circuits (common emitter, common collector and common base) Ability to compute, calculate, analyze, design, assess of field effect transitor (FET, JFET, MOSFET) amplifier circuits (common gate, common sourches and common drain) Ability to calculate, analyze and design filter circuits (low pass filter, high pass filter, bandpass filter), bode plot of amplitude and phase response Ability to analyze and design power eficiency of amplifier circuit, power amplifier, class A, B and AB power amplifier, push pull power amplifier circuits Ability to compute, calculate, analyze, and design of operational amplifier (op-amp) circuit, inverting, non-inverting, summing, voltage
3 E 4 4 S 2 E K

	Ability to analyze and design of basic digital electronics and carnough map Competence: —
Content:	Semiconductor materials and pn-junction, semiconductor diodes, bipolar transistor(bipolar junction transistor), unipolar transistor (field effect transistor), BJT and FET biasing, power amplifier, filter circuit, operational amplifier, comparator, digital electronics
Study/exam achievements:	Students are considered to be competent and pass if at least get 50% of examinations (mid-term test, final test, quizzes), homework, Research based learning.
Forms of Media:	Slides and LCD projectors, blackboards, lab.
Literature:	[Malvino, A.; David J Bates, Electronic Principles, McGraw-Hill, 2007] ([Pustaka utama]) [Dennis L. Eggleston, Basic Electronics for Scientists and engineers, Cambridge University Press, 2011] [Fundametal of Analog Circuits, Second Ed., Prentice Hall] ([Pustakapendukung]) [Storey, N., Electronics; A System Approach, Addison Wesley, 1992] ([Pustakaalternatif])
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